

Vishay Semiconductors

High Performance Schottky Rectifier, 1.0 A

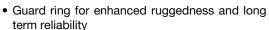


		_	
SMB	(DO-2	14 4	Δ١

PRIMARY CHARACTERISTICS				
I _{F(AV)}	1.0 A			
V_R	40 V			
V _F at I _F	0.38 V			
I _{RM}	9 mA at 125 °C			
E _{AS}	3.0 mJ			
T _J max.	150 °C			
Package	SMB (DO-214AA)			
Circuit configuration	Single			

FEATURES

• Low forward voltage drop





FREE

- Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATION

The VS-10BQ040-M3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	1.0	Α		
V_{RRM}		40	V		
I _{FSM}	t _p = 5 μs sine	430	Α		
V _F	1.0 A _{pk} , T _J = 125 °C	0.38	V		
T _J	Range	-55 to +150	°C		

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-10BQ040-M3	UNITS		
Maximum DC reverse voltage	V_{R}	40	V		
Maximum working peak reverse voltage	V_{RWM}	40	V		

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	I _{F(AV)}	50 % duty cycle at T _L = 122 °C,	rectangular waveform	1.0	Α
Maximum peak one cycle		5 μs sine or 3 μs rect. pulse	Following any rated	430	
non-repetitive surge current	I _{FSM}	10 ms sine or 6 ms rect. pulse	load condition and with rated V _{RRM} applied	40	А
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 1 \text{A}, L = 6 \text{mH}$		3.0	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T_J maximum $V_A = 1.5 \times V_R$ typical		1.0	А



Vishay Semiconductors

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
		1 A	T.1 = 25 °C	0.45	
Maximum forward voltage drop	V _{FM} ⁽¹⁾	2 A	1J=25 C	0.52	V
See fig. 1	V _{FM} (*)	1 A	T _J = 125 °C	0.38	
		2 A		0.50	
Maximum reverse leakage current		T _J = 25 °C	0.1	mA	
See fig. 2	I _{RM}	T _J = 125 °C	V_R = Rated V_R	9.0	IIIA
Typical junction capacitance	C _T	$V_R = 5 V_{DC}$, (test signal range 100 kHz to 1 MHz), 25 °C 115		115	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body 2.0 nH		nH	
Maximum voltage rate of charge	dV/dt	Rated V _R 10 000 V/µ		V/µs	

Note

 $^{^{(1)}}$ Pulse width = 300 μ s, duty cycle = 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		-55 to +150	°C
Maximum thermal resistance, junction to lead	R _{thJL} ⁽²⁾	DC operation	36	°C/W
Maximum thermal resistance, junction to ambient	R _{thJA}		80	C/VV
Approximate weight			0.10	g
Approximate weight			0.003	oz.
Marking device		Case style SMB (DO-214AA)	1	F

Notes

 $[\]frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink

⁽²⁾ Mounted 1" square PCB

Vishay Semiconductors

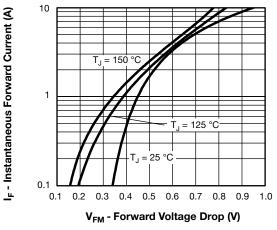


Fig. 1 - Maximum Forward Voltage Drop Characteristics

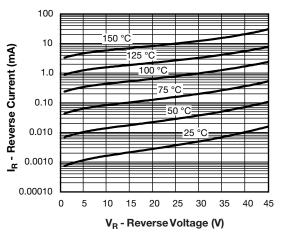


Fig. 2 - Typical Reverse Current vs. Reverse Voltage

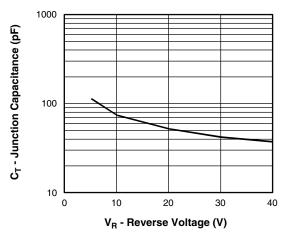


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

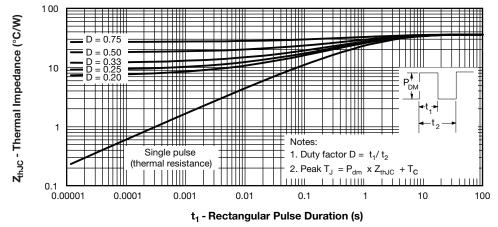


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

Vishay Semiconductors

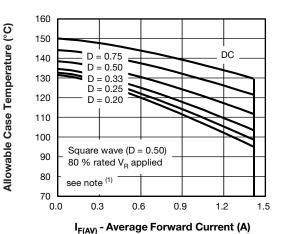


Fig. 5 - Maximum Average Forward Current vs. Allowable Lead Temperature

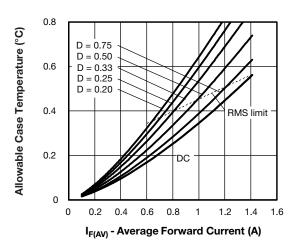


Fig. 6 - Maximum Average Forward Dissipation vs. Average Forward Current

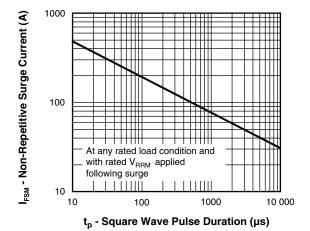


Fig. 7 - Maximum Peak Surge Forward Current vs. Pulse Duration

Note

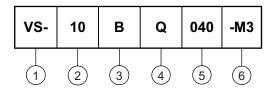
(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}$; $Pd = forward power loss = I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80 \%$ rated V_R



Vishay Semiconductors

ORDERING INFORMATION TABLE





1 - Vishay Semiconductors product

2 - Current rating

3 - B = SMB

4 - Q = Schottky "Q" series

Voltage rating (040 = 40 V)

6 - Environmental digit:

-M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	PREFERRED PACKAGE CODE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION				
VS-10BQ040-M3/5BT	5BT	3200	13" diameter plastic tape and reel		

LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95401		
Part marking information	www.vishay.com/doc?95403		
Packaging information	www.vishay.com/doc?95404		



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Vishay products are not designed for use in life-saving or life-sustaining applications or any application in which the failure of the Vishay product could result in personal injury or death unless specifically qualified in writing by Vishay. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.